MN863440

TFT LCD Gate Driver with 200, 240, 256, or 263 Outputs

Overview

The MN863440 is a TFT LCD gate driver with 200, 240, 256, or 263 2-value outputs. The number of outputs can be selected to be any one of these by the user.

This IC implements 2-value (pseudo 3-value) drive, and provides a cascade-connection pin to support large-screen displays. It is provided in a TCP package.

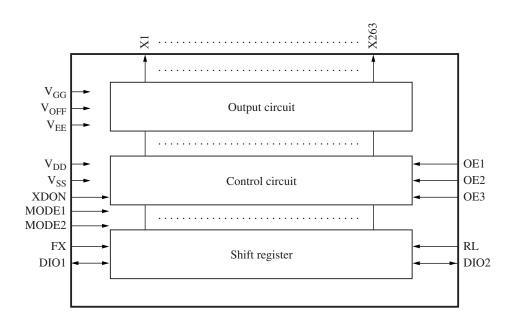
Features

- Adopts a bidirectional shift register system
- Provides an expansion pin so that the number of output pins can be increased.
- Pulse width modulation function (OE1 to OE3)
- Driver operating frequency: 500 kHz (maximum)
- LCD drive voltage: V_{EE} + 40 V (maximum)
- Driver output levels: 2 levels (The low level can be modified.)
- Supports TCP mounting.

Applications

• LCD TV sets

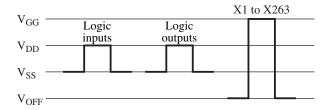
■ Block Diagram



■ Functional Descriptions

1. LCD drive voltages

The MN863440 can provide LCD drive voltages that are negative relative to logic ground.



2. Operation

The MN863440 outputs either the display level (V_{GG}) or the off level (V_{OFF}) from the LCD driver outputs (X1 to X263) under control of the shift data and the OE input signal.

The data shift direction can be controlled with the shift direction switching pin (RL).

The DIO input signal is acquired on the rising edge of FX. The shift register operates and the drive voltages are output with this timing as well. The DIO output is synchronized with the falling edge of FX.

	Start	Data transfer	Carry pulse
RL	pulse input	direction	output
RL = High	DIO1	X1 → X263	DIO2
RL=Low	DIO2	$X263 \rightarrow X1$	DIO1

■ Functional Descriptions (continued)

3. OE function

The outputs can be forced to the display off level regardless of the data in the shift register in sets consisting of every third output pin by setting the OE1, OE2, and OE3 pins to the high level.

This function operates asynchronously with the FX pin.

200 output TCP	240 output TCP	256 output TCP 263 output TC		
MODE1 = Low	MODE1 = Low	MODE1 = High	MODE1 = High	
MODE2 = Low	MODE2 = High	MODE2 = Low	MODE2 = High	
X1 (OE1)	X1 (OE1)	X1 (OE1)	X1 (OE1)	
X2 (OE2)	X2 (OE2)	X2 (OE2)	X2 (OE2)	
X3 (OE3)	X3 (OE3)	X3 (OE3)	X3 (OE3)	
<u> </u>	: :	: :	<u> </u>	
X98 (OE2)	: :	: :	X98 (OE2)	
X99 (OE3)	: :	: :	X99 (OE3)	
X100 (OE1)	: :	: :	X100 (OE1)	
	: :	: :	: :	
	X118 (OE1)	: :	X118 (OE1)	
	X119 (OE2)	: :	X119 (OE2)	
	X120 (OE3)	: :	X120 (OE3)	
		: :	: :	
		X126 (OE3)	X126 (OE3)	
		X127 (OE1)	X127 (OE1)	
		X128 (OE2)	X128 (OE2)	
			X129 (OE3)	
			X130 (OE1)	
			X131 (OE2)	
			X132 (OE3)	
			X133 (OE1)	
			X134 (OE2)	
			X135 (OE3)	
		X136 (OE3)	X136 (OE1)	
		X137 (OE1)	X137 (OE2)	
		X138 (OE2)	X138 (OE3)	
		<u> </u>	<u> </u>	
	X144 (OE1)	: :	X144 (OE3)	
	X145 (OE2)	: :	X145 (OE1)	
	X146 (OE3)	: :	X146 (OE2)	
	: :	: :	: :	

■ Functional Descriptions (continued)

3. OE function (continued)

200 output TCP	240 output TCP	256 output TCP	263 output TCP
X164 (OE2)	: :	: :	X164 (OE2)
X165 (OE3)	: :	: :	X165 (OE3)
X166 (OE1)	: :	: :	X166 (OE1)
: :	: :	: :	: :
X261 (OE3)	X261 (OE1)	X261 (OE2)	X261 (OE3)
X262 (OE1)	X262 (OE2)	X262 (OE3)	X262 (OE1)
X263 (OE2)	X263 (OE3)	X263 (OE1)	X263 (OE2)

Here, (OEn) indicates which of OE1, OE2, and OE3 is the related signal.

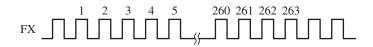
4. XDON function

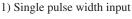
The outputs can be set to the output the display on potential (V_{GG}) regardless of the states of the OEn pins and the shift register data by setting the XDON pin to the low level.

This function operates asynchronously with the FX pin. This pin is pulled up.

5. Carry input (DIO1, DIO2)

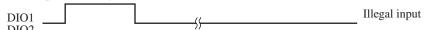
The waveform input to the carry input must meet the following conditions.



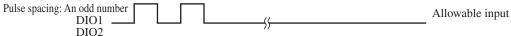




2) Input with a width of 2 pulses or longer



3) Double pulse input



4) Double pulse input

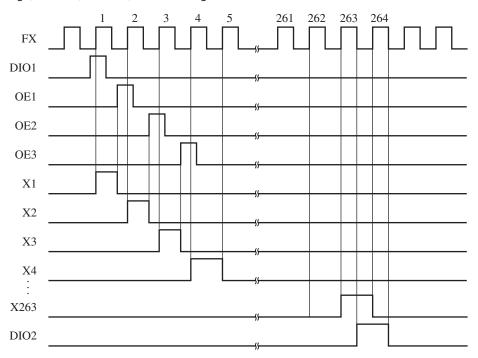


■ Pin Descriptions

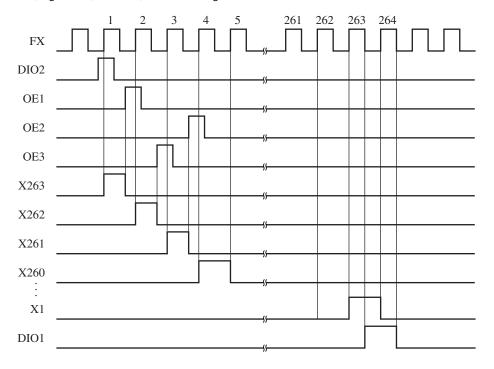
Pin Name	I/O	Function	Description			
FX	I	Shift register clock input	The start pulse is acquired and the shift register shifted on th FX rising edge. The carry pulse is output on the FX falling edge.			
RL	I	Right shift/left shift selection input	RL = High: $X1 \rightarrow X263$ (Left shift) RL = Low: $X263 \rightarrow X1$ (Right shift)			
DIO1	I/O	Start pulse input and carry		DIO1	DIO2	
DIO2		pulse output	RL = High	I	0	
			RL = Low	0	I	
MODE1 MODE2	I	Output pin count switching	MODE1	MODE2	LCD outputs	
MODE2		inputs	High	High	263	
			High	Low	256	
			Low	High	240	
			Low	Low	200	
OE1 to OE3	I	Display signal enable/disable inputs	When OEn is high, the corresponding LCD drive output pare set to the display off potential (V _{OFF}) asynchronously with the FX pin, regardless of the states of the shift register and other input data. See 3. OE function in the Functional Descriptions section			
X1 to X263	0	LCD drive outputs	These pins output, in synchronization with the FX rising ϵ either the V_{GG} or the V_{OFF} voltage level according to the shift register data and the states of the OE1 to OE3, DIO and DIO2 pins.			
$V_{ m GG}$	Power	LCD drive output block power supply LCD drive supply 1			ters and output be LCD drive voltage.	
V _{OFF}	Power	LCD drive supply 2	Supplies an LC	D drive voltage	•	
V_{EE}	Power	V _{GG} system ground				
V_{DD}	Power	3 V system logic power supply	Power supply u	sed for the 3 V	system logic circ	cuits.
V_{SS}	Power	V _{DD} system ground				

■ Basic Waveforms

1. RL = High, left shift, MODE1, MODE2 = high

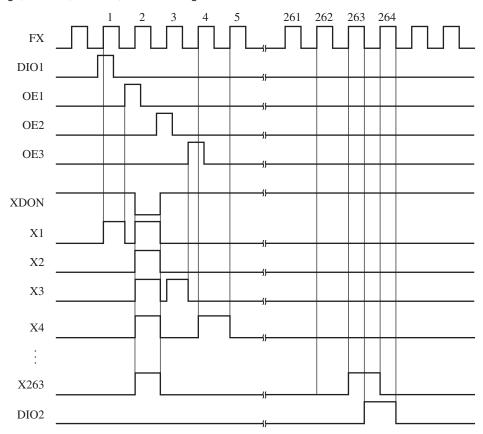


2. RL = Low, right shift, MODE1, MODE2 = high



■ XDON Usage Example

• RL = High, left shift, MODE1, MODE2 = high



■ Electrical Characteristics

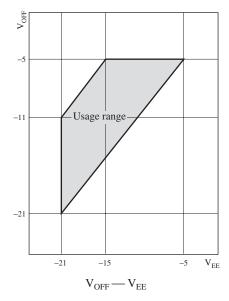
1. Absolute Maximum Ratings at V_{SS} = 0 V

Item	Symbol	Rating	Unit
Supply voltage 1	V_{DD}	- 0.3 to +4.5	V
Supply voltage 2	V_{GG}	V _{EE} to V _{EE} +44	V
Drive voltage	V _{OFF}	V_{EE} – 0.3 to V_{GG} +0.3	V
Supply voltage 3	V_{EE}	- 24 to +0.3	V
Digital input voltage	V_{I}	- 0.3 to V _{DD} +0.3	V
Operating and storage temperature range	Ta	-30 to +85	°C
Operating ambient temperature	T_{opr}	-20 to +75	°C
Storage temperature	T_{stg}	-55 to +120	°C

- Note) 1. The absolute maximum ratings are limit values for stresses applied to the chip so that the chip will not be destroyed. Operation is not guaranteed within these ranges.
 - The operating and storage temperature range is the temperature range over which the chip will not be damaged even if operated. Note that performance is not guaranteed throughout this range.
 - 3. These ratings are guaranteed values when the standard Panasonic package is used.
 - The power supply voltages must meet the condition V_{EE} ≤ V_{GG} at all times, including when power is being applied, during operation, and when power is being turned off.
 - 5. When power is applied, certain sequences of power application can cause large currents to flow and permanently damage the IC. To avoid this problem, first apply V_{DD} , and then, after V_{DD} has reached 90% of its set voltage, apply V_{EE} , V_{GG} , and V_{OFF} .

2. Operating Conditions at $V_{SS} = 0 \text{ V}$, $T_{opr} = -20^{\circ}\text{C}$ to $+75^{\circ}\text{C}$

Item	Symbol	Condition	Min	Тур	Max	Unit
Operating supply voltage 1	V_{DD}		2.3	_	3.6	V
Operating supply voltage 2	V_{GG}		10	_	V _{EE} +40	V
Operating supply voltage 3	V _{EE}		-21	_	-5	V
Operating supply voltage 3	V _{OFF}	$-21 \le V_{EE} \le -15$	V _{EE}		V _{EE} +10	V
		$-15 < V_{EE} < -5$	V _{EE}		-5	



Note) These ratings are guaranteed values when the standard Panasonic package is used.

■ Electrical Characteristics (continued)

3. DC Characteristics at $V_{SS} = 0 \text{ V}$, $T_{opr} = -20^{\circ}\text{C}$ to $+75^{\circ}\text{C}$

Item	Symbol	Condition	Min	Тур	Max	Unit
Operating supply current (V _{DD})	I _{DD}	$f_{EX} = 15.7 \text{ kHz}$			800	μА
operating suppry current (* DD)	-DD	$f_{DIO} = 60 \text{ Hz}$			000	μ21
		$V_{DD} = 3.0 \text{ V}$				
Operating supply current (V _{GG})	I_{GG}	$V_{OFF} = -15 \text{ V}$	_	_	300	μΑ
		$V_{GG} = 15 \text{ V}$				
		With no output load				
Standby mode current	I_{DS}	In standby mode	_	_	600	μΑ
consumption (V _{DD})		$V_{DD} = 3.0 \text{ V}$				
Standby mode current	I_{GS}	$V_{OFF} = -15 \text{ V}$	_	_	100	μΑ
consumption (V _{GG})	4 OF2 MG	$V_{GG} = 15 \text{ V}$				
		DDE1, MODE2	0.0		X7.	X 7
High-level input voltage	V _{IH1}		$0.8 \times V_{DD}$		V _{DD}	V
Low-level input voltage	V _{IL1}		0		$0.2 \times V_{DD}$	V
Input leakage current	I _{LI1}		-10		10	μΑ
	DON	I				
High-level input voltage	V _{IH2}		$0.8 \times V_{DD}$		V_{DD}	V
Low-level input voltage	V _{IL2}		0		$0.2 \times V_{DD}$	V
Pull-up resistance	R _{PU}	$V_{DD} = 3.0 \text{ V}$	10	_	100	kΩ
3) I/O pins DIO1, DIO2						
High-level input voltage	V_{IH3}		$0.8 \times V_{DD}$	_	V_{DD}	V
Low-level input voltage	V _{IL3}		0	_	$0.2 \times V_{DD}$	V
High-level output voltage	V _{OH}	–100 μΑ	$V_{DD} - 0.4$	_	_	V
Low-level output voltage	V _{OL}	100 μΑ	_	_	0.4	V
4) LCD drive voltage input pir	V _{OFF}					
Input leakage current	V _{LI1}		-50	_	50	μΑ
5) LCD drive output pins	X1 ~ X263					
Output leakage current	I _{LO1}		-50	_	50	μΑ
Output on resistance	RON-V _{GG}	V _{GG} = 15 V	200	400	800	Ω
		$V_{OFF} = -15 \text{ V}$				
		$V_{OM} = V_{GG} - 0.5 \text{ V}$				
		V _{OM} is the X1 to X263				
		applied voltage.				
	RON-V _{OFF}	$V_{GG} = 15 \text{ V}$	200	400	800	
		$V_{EE} = -15 \text{ V}$				
		$V_{OFF} = -15 \text{ V}$				
		$V_{OM} = V_{OFF} + 0.5 \text{ V}$				
		V _{OM} is the X1 to X263				
		applied voltage.				

Note) These ratings are guaranteed values when the standard Panasonic package is used.

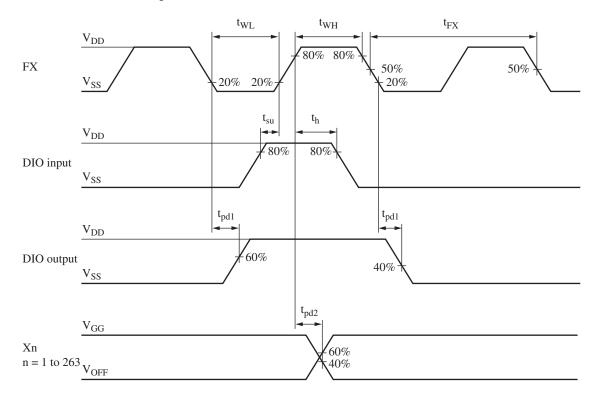
■ Electrical Characteristics (continued)

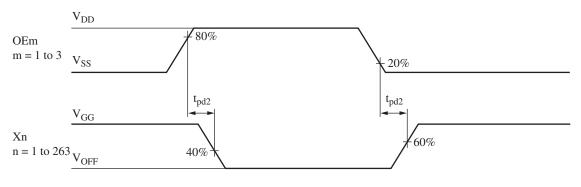
4. AC Characteristics at V_{SS} = 0 V, T_{opr} = -20°C to +75°C

Item	Symbol	Condition	Min	Тур	Max	Unit
Clock period	t _{FX}		2.0	_	_	μs
Clock high-level pulse width	t _{WH}		700	_	_	ns
Clock low-level pulse width	t_{WL}		700		_	ns
DIO data setup time	t _{su}		300	_	_	ns
DIO data hold time	t _h		300	_	_	ns
DIO output delay time	t _{pd1}	CL = 50 pF	_	_	600	ns
Xn output delay time	t _{pd2}	CL = 300 pF	_	_	800	ns

Note) These ratings are guaranteed values when the standard Panasonic package is used.

AC Characteristics Timing Charts





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